

Midterm Review

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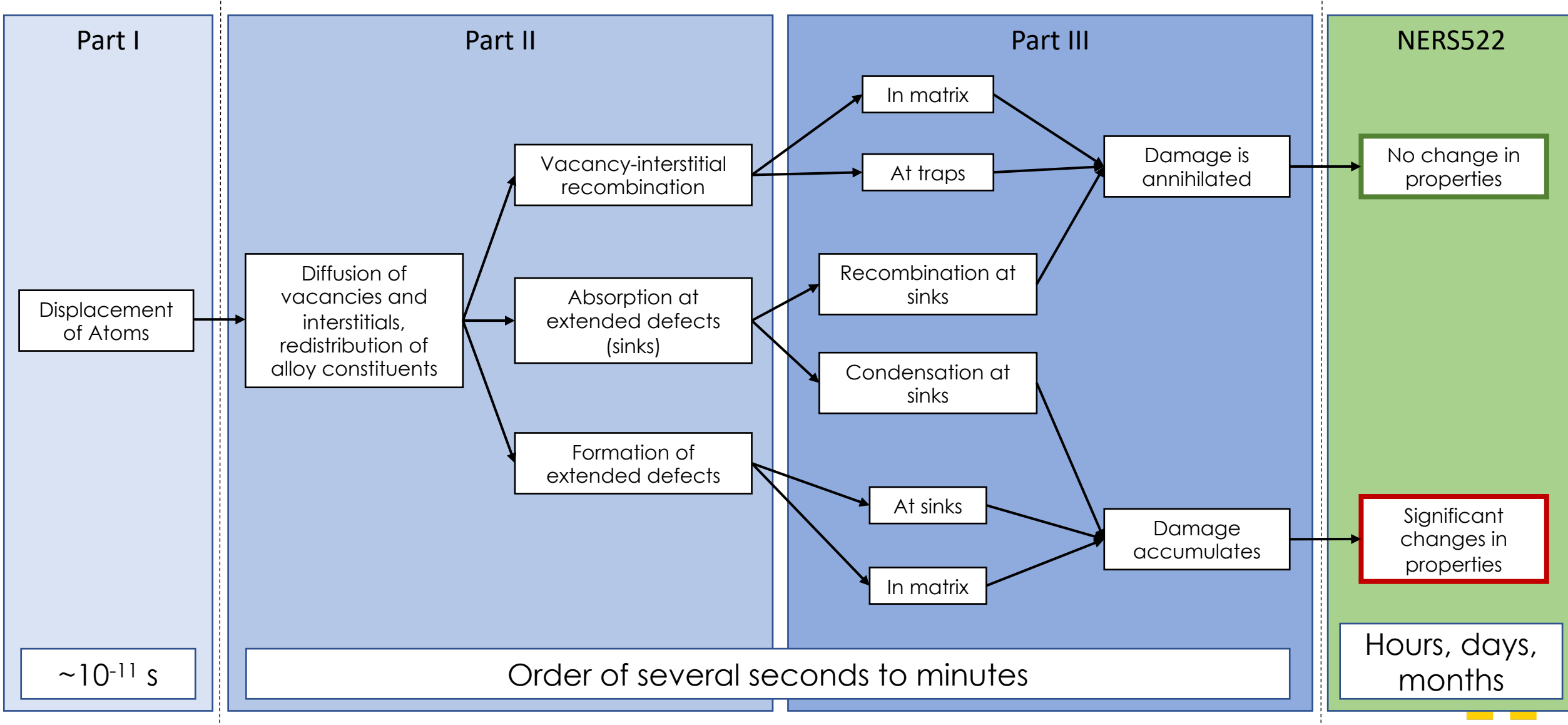
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**NUCLEAR ENGINEERING &
RADIOLOGICAL SCIENCES**
UNIVERSITY OF MICHIGAN

NERS 521 Study Guide

Flow chart for radiation damage



Summary of topics covered

Part I: The radiation damage event

Objective: Develop a fundamental understanding of the physics of the radiation damage event

Day	Date	Topic	Lecture Notes	Assignments	Other resources/details
Monday	Aug. 30	Introduction	Recording / No notes	-	-
Wednesday	Sept. 1	Basic particle interactions	Recording / Notes	-	Alt. basic particle derivation
Monday	Sept. 6	No lecture - Labor Day	-	-	-
Wednesday	Sept. 8	Collision Kinematics	Recording / Notes	PS#1	Flux/Fluence/Cross-sections/energy transfer quick review
Monday	Sept. 13	Interatomic Potentials & Cross Sections	Recording / Notes	-	Displacement Integrals
Wednesday	Sept. 15	Simple Disp. Theory	Recording / Notes	-	Cross section conversions
Monday	Sept. 20	Energy loss & K-P modifications	Recording / Notes	PS1 due	
Wednesday	Sept. 22	Focus, Channel, Range	Recording / Notes	PS1 Sol.	
Monday	Sept. 27	Damage Cascades	Recording / Notes	PS#2	Arc-dpa Paper

Summary of topics covered

Part II: Point Defect Generation, Recombination, and Mobility

Objective: Apply knowledge from the radiation damage event to determine the point defect generation in material systems

Day	Date	Topic	Lecture Slides	Assignments	Other resources
Wednesday	Sept. 29	Point Defects	Recording / Notes		
Monday	Oct. 4	Defect Motion	Recording / Notes	PS 2 due	
Wednesday	Oct. 6	Point Defect Kinetics	Recording / Notes	PS2 Sol.	
Monday	Oct. 11	Kinetics + RED	Recording / Notes	PS3	
Wednesday	Oct. 13	Defect Reactions	Recording / Notes	PS3 updated	

Energy Transfer to the PKA (T)

The energy transfer due to a hard sphere collision can be calculated using:

$$T = \frac{\gamma}{2} E_i (1 - \cos \theta)$$

The maximum energy transfer, \hat{T} is then:

- E_i
- γE_i
- $\frac{\gamma E_i}{2}$

Energy Transfer to the PKA (T)

The energy transfer due to a hard sphere collision can be calculated using:

$$T = \frac{\gamma}{2} E_i (1 - \cos \theta)$$

The average energy transferred is then:

- E_i
- γE_i
- $\frac{\gamma E_i}{2}$

Units of Radiation Damage (T)

DPA stands for:

- Displacements per atom
- Damage per atom
- Displacement potential of an atom
- Down plane acceleration

Classic scattering integral equation

The classic scattering angle equation enables the evaluation of the scattering angle based on the interaction between two particles and is given as:

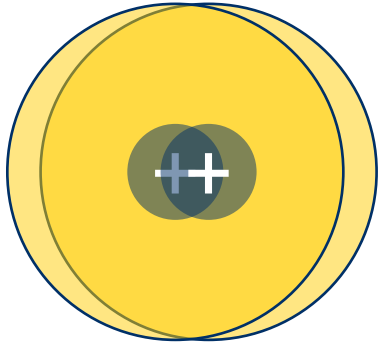
$$\phi = \pi - 2 \int_{\infty}^p \frac{b}{r^2} \frac{dr}{\sqrt{1 - \frac{V(r)}{\Sigma} - \frac{b^2}{r^2}}}$$

What is p and $V(r)$ in this equation? What is the importance of these parameters in determining the radiation damage event?

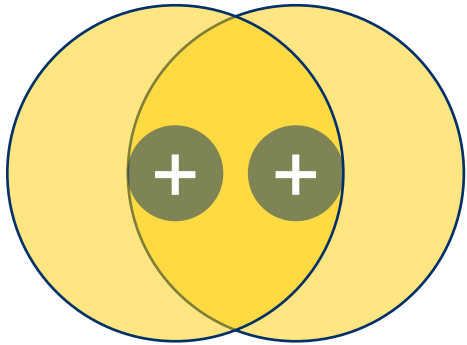
Interatomic Potentials

1. When p (or r in slide notes) is less than radius of a typical lattice atom (a_0) the electrons are in the internuclear space which screen the total nuclear charge. What is the appropriate interatomic potential to use in this case?
2. The interatomic potential will change depending on the type of ion and the incident ion energy for an ion irradiation experiment.
 - True
 - False

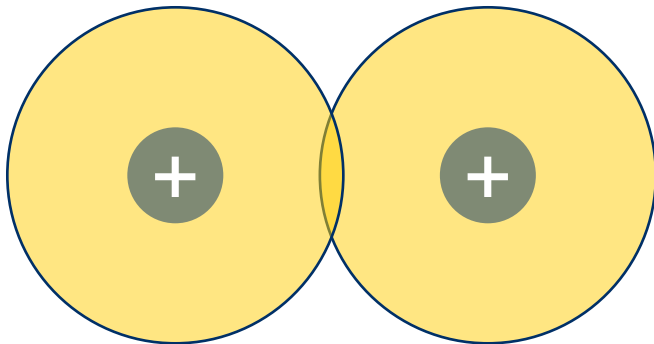
Importance of Interatomic Potentials



$R < \text{K-shell radius}$
(Coulomb)



$\text{K-shell radius} < R < \text{Lattice Constant}$
(Screened Coulomb)



$< R < \text{Lattice Constant}$
(Born-Mayer)

Potential	Equation	Range of Applicability	Definitions	Eqn in text
Hard sphere	$0 \text{ for } r > r_0$ $\infty \text{ for } r < r_0$	$10^{-1} < T < 10^3 \text{ eV}$	$r_0 = \text{size of atom}$	(1.46)
Born-Mayer	$V(r) = A \exp(-r/B)$	$10^{-1} < T < 10^3 \text{ eV}$ $a_0 < r \leq r_e$	A, B determined from elastic moduli	(1.47)
Simple Coulomb	$\frac{Z_1 Z_2 e^2}{r}$	light ions of high energy $r \ll a_0$		(1.48)
Screened Coulomb	$\left(\frac{Z_1 Z_2 e^2}{r} \right) \exp(-r/a)$	Light ions $r < a_0$	$a_0 = \text{Bohr radius}$ $a = \text{screening radius}$	(1.49)
Brinkman I	$\frac{Z^2 e^2}{r} e^{(-r/a)} \left(1 - \frac{r}{2a} \right)$	$r < a$	$a \cong a_0 / Z^{1/3}$	(1.51)
Brinkman II	$\frac{A Z_1 Z_2 e^2 \exp(-Br)}{1 - \exp(-Ar)}$	$Z > 25$ $r < 0.7 r_e$	$A = \frac{0.95 \times 10^{-6}}{a_0} Z^{7/2}$ $B = Z^{1/3} / C a_0$ $C \cong 1.5$	(1.52)
Firsov	$\frac{Z_1 Z_2 e^2}{r} \chi \left[\left(Z_1^{1/2} + Z_2^{1/2} \right)^{2/3} \frac{r}{a} \right]$	$r \leq a_0$	χ is screening function	(1.56)
TFD Two Center	$\frac{Z^2 e^2}{r} \chi \left(Z^{1/3} \frac{r}{a} \right) - \alpha Z + \bar{\Lambda}$	$r < r_b (3a_0)$	$r_b = \text{radius at which the electron cloud density vanishes}$	(1.57)
Inverse square	$\frac{2E_r}{e} (Z_1 Z_2)^{5/6} \left(\frac{a_0}{r} \right)^2$	$a/2 < r < 5a$	$E_r = \text{Rydberg energy} = 13.6 \text{ eV}$	(1.59)

Total Cross Section

The interatomic potential, scattering integral, energy transfer and relationships between differential cross sections are all used to determine the total cross section for a particle-particle interaction.

-True

-False

N for common crystal structures

N is the atomic volume of the cell and can be determined by:

$$N = \frac{\textit{num. atoms in a unit cell}}{a_0^3}$$

What then are the number atoms in the unit cell for:

-BCC

-FCC

Displacement Energy E_d

Based on the Kinchin-Pease model, if an energetic particle has an energy less than E_d , then what happens to the struck atom?

- The struck atom is displaced from the lattice site and is presumed to come to rest at a location in the lattice different from its previous position
- The struck atom is pressed to resume to its lattice site after interaction

Displacement energy, E_d , is crystal directionally dependent.

- True
- False

Kinchin Pease Approach I

You are asked to calculate the dpa/s based on a monoenergetic flux of neutrons into BCC iron. You determine you need to calculate the damage cross section, $\sigma_D(E_i)$, using your notes you determine the equation to do this calculation is:

$$\sigma_D(E_i) = \int_{\check{T}}^{\hat{T}} \sigma_s(E_i, T) v(T) dT = \frac{\sigma_s(E_i)}{\gamma E_i} \int_{\check{T}}^{\hat{T}} v(T) dT <p>$$

What values should you use for \check{T} and \hat{T} ?

Kinchin Pease Approach II

You have correctly identified in the previous slide that \hat{T} is the maximum energy transfer. You calculate this using $T_{max} = \hat{T} = \gamma E_i$ and get a value of $0.025 MeV$. Based on this value is using the following equation the correct approach?

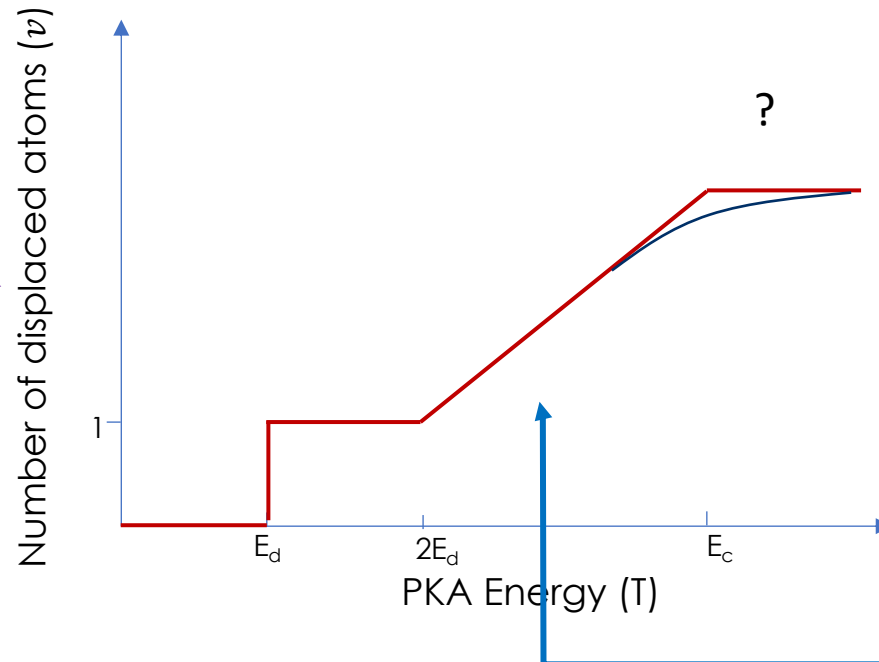
$$\sigma_D(E_i) = \frac{\sigma_s(E_i)}{\gamma E_i} \left(\int_0^{E_d} 0 dT + \int_{E_d}^{2E_d} 1 dT + \int_{2E_d}^{E_c} \frac{T}{2E_d} dT + \int_{E_c}^{\gamma E_i} \frac{E_c}{2E_d} dT \right)$$

Hint: The atomic weight of Fe is 55.85.

Point Defect Kinetic Equations

$$\frac{\partial C_v}{\partial t} = \boxed{K_0} - K_{iv}C_iC_v - \sum_s K_{vs}C_vC_s + D_v\nabla^2 C_v$$

$$\frac{\partial C_i}{\partial t} = \boxed{K_0} - K_{iv}C_iC_v - \sum_s K_{is}C_vC_s + D_i\nabla^2 C_i$$



$$T = \frac{1}{2} \frac{4mM}{(m+M)^2} (1 - \cos \varphi) E_i$$

$$\gamma = \frac{4mM}{(m+M)^2}$$

$$T = \frac{1}{2} \gamma (1 - \cos \varphi) E_i$$

$$T_{max} = \gamma E_i$$



Stopping Powers

A high energy (>1 MeV) heavy ion is injected into a bulk material. The ions will undergo energy loss as it passes through the material and come to rest at some position away from the implantation surface. The primary energy loss at high energy (e.g. early in range) is _____ and at low energy is _____.

- Nuclear, electronic
- Electronic, nuclear

Focusing and channelling

Most crystalline materials will experience focusing and/or channeling events when irradiated with energetic particles. This is due to preferential directions and planes in the atomic structure. Focusing and channeling act then to increase the number of displacements under irradiation.

- True
- False

Range

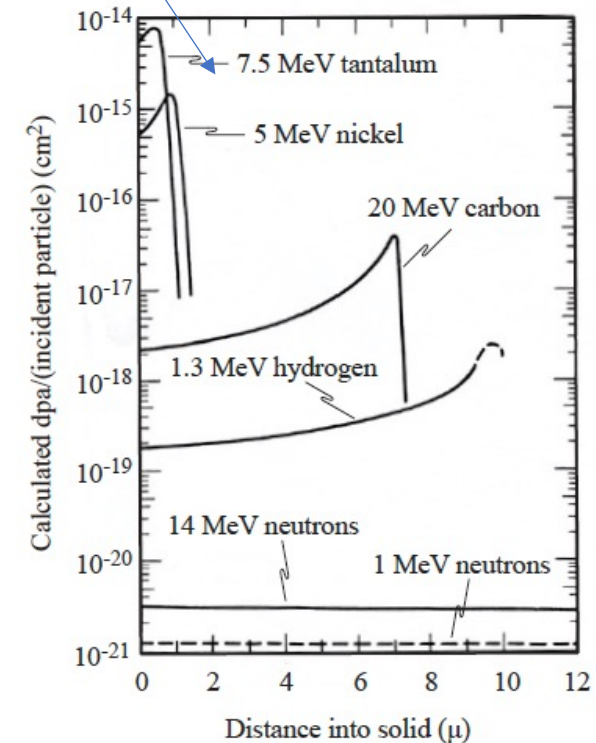
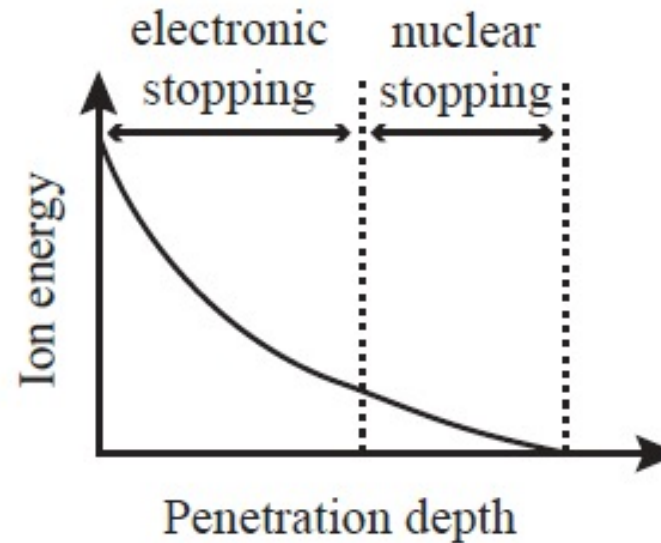
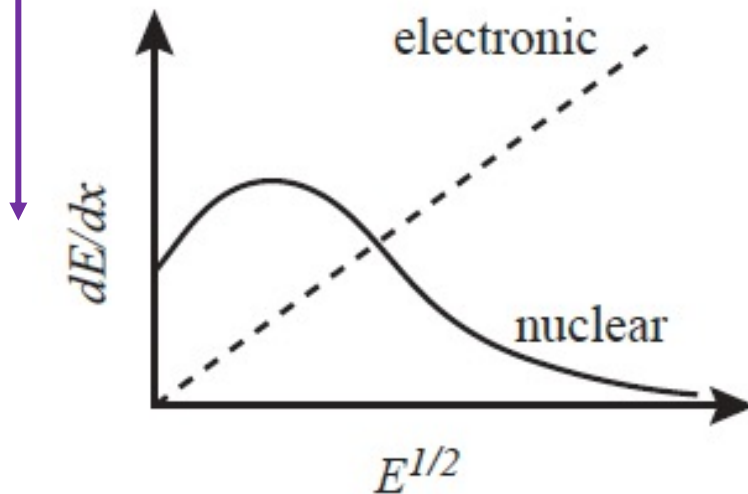
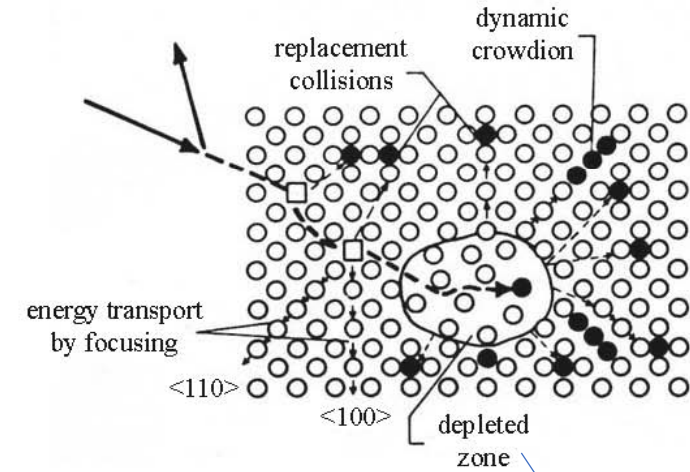
At high energy, ions will typically undergo _____ that lead to _____. *At the energy is decreased of the ions they will undergo _____ that leads to _____. Once the the energy reaches below _____ the ions no longer cause displacements and come to rest a short distance further into the material.*

- High angle collisions; high energy loss; low angle collisions; low energy loss; E_d
- Low angle collisions; high energy loss; high angle collisions; low energy loss; E_d
- Low angle collisions; low energy loss; high angle collisions; high energy loss; E_c
- Low angle collisions; low energy loss; high angle collisions; high energy loss; E_d

Point Defect Kinetic Equations

$$\frac{\partial C_v}{\partial t} = K_0 - K_{iv}C_iC_v - \sum_s K_{vs}C_vC_s + D_v\nabla^2 C_v$$

$$\frac{\partial C_i}{\partial t} = K_0 - K_{iv}C_iC_v - \sum_s K_{is}C_vC_s + D_i\nabla^2 C_i$$



Cascades and Damage

The cascade morphology is strongly dependent on the mass of the incident ion and its energy.

-True

-False

Heavy ions will commonly cause small scale cascades with vacancy rich cores.

-True

-False

The Kinchin Pease and NRT approach don't account for enhanced recombination in metals in a cascade

-True

-False

Point Defects

You are asked to calculate the concentration of vacancies and interstitials at $\frac{1}{3}$ the melting point of a metal. You find that $C_i^{eq} > C_v^{eq}$, should you check your work?

- True
- False

The primary point defect diffusion mechanisms are (select all that apply):

- Exchange
- Ring
- Vacancy
- Interstitial
- Interstitialcy
- Dumbbell
- Crowdion

Point Defect Kinetic Equations

- If we neglect clustering:

$$\frac{\partial C_v}{\partial t} = K_0 - K_{iv}C_iC_v - \sum_s K_{vs}C_vC_s + D_v\nabla^2 C_v$$

$$\frac{\partial C_i}{\partial t} = K_0 - K_{iv}C_iC_v - \sum_s K_{is}C_vC_s + D_i\nabla^2 C_i$$

- Example of defect absorption to cavities:

$$\frac{\partial C_v}{\partial t} = K_0 - K_{iv}C_iC_v - z_v p_d D_v C_v + 4\pi R_c N_c D_v C_v$$

$$\frac{\partial C_i}{\partial t} = K_0 - K_{iv}C_iC_v - z_v p_d D_i C_i + 4\pi R_c N_c D_i C_i$$

Defect Reactions I

For a low temperature, low sink density regime the order of different regimes for C_v and C_i as a function of irradiation time are:

- Mutual recombination; build up without reaction; sinks contribute to interstitial annihilation; sinks annihilate both vacancies and interstitials
- Build up without reaction; mutual recombination; sinks contribute to interstitial annihilation; sinks annihilate both vacancies and interstitials
- Build up without reaction; sinks contribute to interstitial annihilation; sinks annihilate both vacancies and interstitials; mutual recombination

The effect of increasing the sink strength in the system would be to move t_3 closer to t_2 .

-True

-False

Defect Reactions II

You are asked to calculate the time when vacancies arrive at sinks to determine the time to reach steady state conditions in a material using the point defect rate theory equations. Your answer comes out to be only a few seconds and a fractional dose. Should you go back and check your work?

-Yes

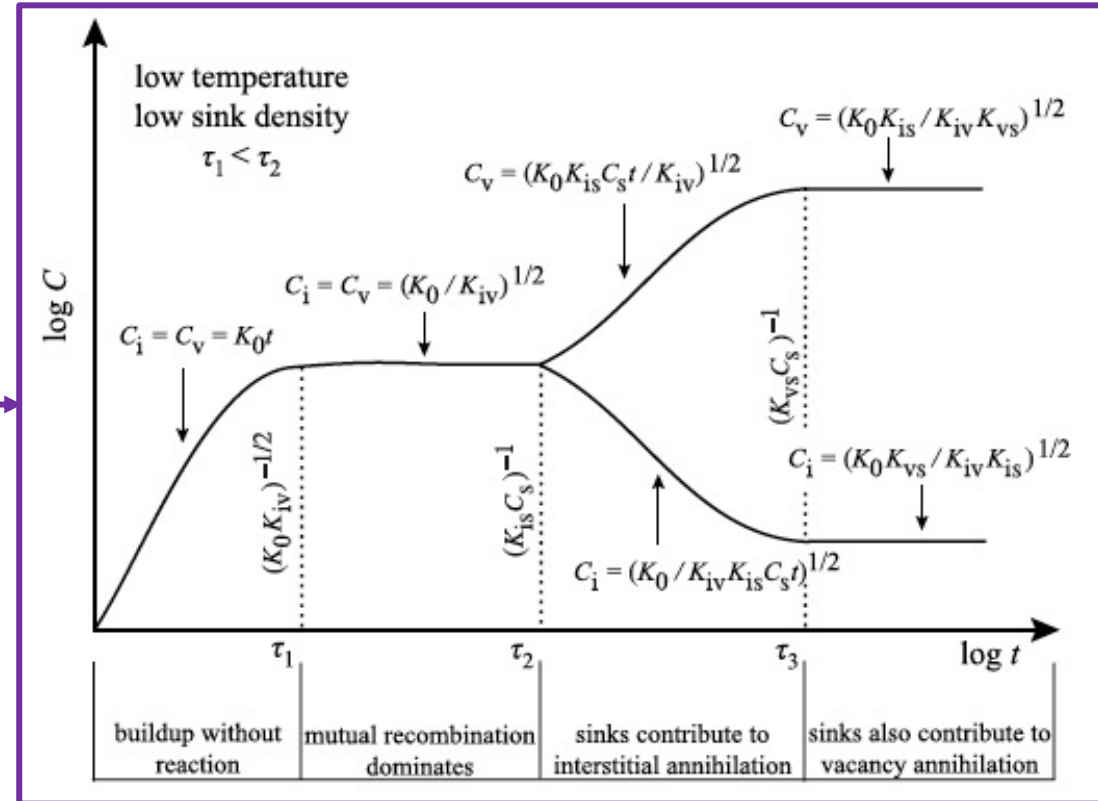
-No

-There is no time to check my work either way because I didn't study for the exam. I am just happy to have numbers on the page.

Point Defect Kinetic Equations

$$\frac{\partial C_v}{\partial t} = K_0 - K_{iv} C_i C_v - \sum_s K_{vs} C_v C_s + D_v \nabla^2 C_v$$

$$\frac{\partial C_i}{\partial t} = K_0 - K_{iv} C_i C_v - \sum_s K_{is} C_v C_s + D_i \nabla^2 C_i$$



Diffusion during irradiation

Irradiation in metals under irradiation will tend to accelerate diffusion at intermediate temperatures due to increases in the point defect concentrations due to displacements.

- True
- False

Diffusion-based processes tend to be controlled by vacancy-based diffusion.

- True
- False

At low irradiation temperatures radiation effects tend to be _____ because of _____ diffusion and at high temperatures radiations effects tend to be _____ because of _____ resulting in bell-curve shaped graphs of radiation effect magnitude as a function of irradiation temperature.

- Recombination dominated; sluggish; thermal diffusion limited; high concentration of vacancies
- Thermal diffusion limited; sluggish; recombination dominated; high defect sink concentration
- Damage limited; high; moderate; high concentration of interstitials

Sinks and defect reactions

Grain boundaries and voids act as _____.

- Neutral sinks
- Biased sinks
- Variable sinks

You are asked to derive the reaction rate for a platelet precipitate and get a pre-factor of 4π to account for the geometry. How much confidence to you have in your answer?

- Low
- Moderate
- High

Point Defect Kinetic Equations

$$\frac{\partial C_v}{\partial t} = K_0 - K_{iv}C_iC_v - \sum_s K_{vs}C_vC_s + D_v\nabla^2 C_v$$

$$\frac{\partial C_i}{\partial t} = K_0 - K_{iv}C_iC_v - \sum_s K_{is}C_vC_s + D_i\nabla^2 C_i$$

- Sinks can behave differently:
 - Neutral sinks: Neutral sinks show no preference for capturing one type of defect over another. Examples are voids and grain boundaries
 - Biased sinks: Biased sinks show a preferential attraction for one defect over another. Examples are network dislocations.
 - Variable sinks: Variable sinks act as traps for defects which hold the defect but preserve its identity until annihilation or it is released. Examples are coherent precipitates.

